FISEVIER

Contents lists available at ScienceDirect

Journal of Power Sources

journal homepage: www.elsevier.com/locate/jpowsour



Divalent-doped Na₃Zr₂Si₂PO₁₂ natrium superionic conductor: Improving the ionic conductivity via simultaneously optimizing the phase and chemistry of the primary and secondary phases



Mojtaba Samiee ¹, Balachandran Radhakrishnan ¹, Zane Rice, Zhi Deng, Ying Shirley Meng, Shyue Ping Ong**, Jian Luo*

Department of NanoEngineering, University of California San Diego, 9500 Gilman Drive, Mail Code 0448, La Jolla, CA 92093, USA

HIGHLIGHTS

- The aliovalent doping effects in NASICON investigated via experiments and modeling.
- Both bulk and grain boundary ionic conductivities considered.
- Optimized ionic conductivity of 2.7 mS/cm achieved via mechanistic understanding.
- Simultaneous optimization of bulk and grain boundary phases proven essential.
- A new direction to improve the ionic conductivity of solid electrolytes suggested.

ARTICLE INFO

Article history: Received 8 November 2016 Received in revised form 7 February 2017 Accepted 12 February 2017

Keywords: NASICON Doping Solid-state electrolyte Grain boundary conductivity Sodium superionic conductor

ABSTRACT

NASICON is one of the most promising sodium solid electrolytes that can enable the assembly of cheaper and safer sodium all-solid-state batteries. In this study, we perform a combined experimental and computational investigation into the effects of aliovalent doping in NASICON on both bulk and grain boundary (secondary phase) ionic conductivity. Our results show that the dopants with low solid solubility limits in NASICON lead to the formation of a conducting (less insulating) secondary phase, thereby improving the grain boundary conductivity measured by electrochemical impedance spectroscopy (including grain-boundary, secondary-phase, and other microstructural contributions) that is otherwise hindered by the poorly-conducting secondary phases in undoped NASICON. This is accompanied by a change in the Si/P ratio in the primary NASICON bulk phase, thereby transforming monoclinic NASICON to rhombohedral NASICON. Consequently, we have synthesized NASICON chemistries with significantly improved and optimized total ionic conductivity of 2.7 mS/cm. More importantly, this study has achieved an understanding of the underlying mechanisms of improved conductivities via doping (differing from the common wisdom) and further suggests a new general direction to improve the ionic conductivity of solid electrolytes via simultaneously optimizing the primary bulk phase and the microstructure (including grain boundary segregation and secondary phases).

© 2017 Elsevier B.V. All rights reserved.

1. Introduction

The development of all-solid-state rechargeable alkali-ion batteries is an important step towards safer, higher energy density

E-mail addresses: ongsp@eng.ucsd.edu (S.P. Ong), jluo@alum.mit.edu (J. Luo).

¹ M.S. and B.R. contributed equally to this work.

storage for large-scale applications such as automotive and grid storage. A key component in such an energy storage device will be the solid-state electrolytes with extremely high alkali ionic conductivities, also known as alkali superionic conductors, with room temperature conductivities in excess of 1 mS/cm being a typical target.

Among the known superionic conductors, the NAtrium SuperIonic CONductor (NASICON) family of compounds, with general formula Na_{1+x}Zr₂Si_xP_{3-x}O₁₂ (0 \leq x \leq 3, and Zr can be substituted with other metals or mixture of metals), which has first been

^{*} Corresponding author.

^{**} Corresponding author.

developed by Hong and Goodenough in 1976 [1,2], are arguably one of the most well-known and studied. Originally conceived as a replacement for β-alumina in high-temperature Na-S batteries, NASICON-based compounds have nevertheless garnered significant interest for low/room-temperature applications as electrodes and solid electrolytes for both Li and Na-ion rechargeable batteries [3–6]. Unlike sulfide solid electrolytes [7–11], NASICONs are oxides, which are considerably more air and moisture stable [12–15]. However, the major challenge for NASICONs thus far are their typically moderate-to-low total (bulk plus grain boundary) ionic conductivities at room temperature (~0.1 mS/cm) due to the poorly-conducting ZrO₂ phases formed at grain boundaries [16-20]. Tetragonal Na₃PO₄ is another phase formed at grain boundaries of NASICONs with different synthesis procedures that has received much less attention in literature [4,13]. It should be noted that the so-called "grain boundary conductivity" (measured by electrochemical impedance spectroscopy) in fact represents the combination of the (often coupled) contributions from grain boundaries, secondary phases, and other microstructural features (e.g., the size and distribution of the primary and secondary phases, along with any interfacial effects at the hetero-phase boundaries). In fact, this current study focused more on the effects of secondary phases (precipitated at grain boundaries) than the actual grain boundaries themselves, although we recognize that the latter, the actual grain boundaries (including grain boundary adsorption/ segregation and possible formation of nanoscale interfacial phases at grain boundaries; see, e.g., a recent review [51] for elaboration), can also make significant contributions to a blocking effect.

There are two known phases of NASICONs — a rhombohedral $R\overline{3}c$ phase and a monoclinic C2/c phase that is formed, for example, by Na_{1+x}Zr₂Si_xP_{3-x}O₁₂ for 1.8 $\leq x \leq$ 2.2 at temperatures below 160 °C — that are related to each other by a small rotational distortion. Fig. 1 shows the rhombohedral and monoclinic crystal structures, which comprises corner-sharing SiO₄/PO₄ tetrahedra and ZrO₆ octahedra. In the rhombohedral form, two distinct Na sites M₁ and M₂ form a 3D diffusion network, while the monoclinic distortion splits the M₂ sites into M_2^{α} and M_3^{β} sites.

Recently, there have been several efforts aimed at improving the ionic conductivity of NASICONs by aliovalent doping [4,5,21]. Jolley et al. studied the effect of aliovalent dopants (Ni²⁺, Zn²⁺, Al³⁺, Fe³⁺, Y³⁺) on the ionic conductivity of NASICON. Although all dopants provided room temperature conductivities higher than undoped NASICON, only Co²⁺ doped NASICON provided a conductivity of higher than 1 mS/cm (1.55 mS/cm) at room temperature [4]. However, a Co-based NASICON is unlikely to be a good solid electrolyte candidate due to the redox active nature of Co metal. More recently, Ma et al. synthesized Sc³⁺-doped NASICON that achieved

an overall ionic conductivity of 4.0 mS/cm at room temperature, which is very similar to the value (3.7 mS/cm) obtained in a proprietary compound NASICON reported by Ceramatec [5,22], although Sc is neither an earth-abundant nor a cost-effective doping element. Ma et al. attributed the improvement in bulk conductivity to a higher Na concentration in doped NASCION because substitution of Zr⁴⁺ ions with M³⁺/M²⁺ ions, and the enhancement in grain boundary conductivity to the improved microstructure from the solution-assisted solid-state synthesis procedure. However, the improvement in grain boundary conductivity can also be inferred from normalized Nyquist plots of aliovalent-doped NASICON synthesized by solid-state reaction method [4].

In this work, we present a comprehensive experimental and first principles study of the effect of earth-abundant divalent dopants such as Mg²⁺ and Ni²⁺ on the ionic conductivity of NASICON Na_{1+x}Zr₂Si_xP_{3-x}O₁₂, with an emphasis on understanding the underlying mechanisms of conductivity improvements, particularly the interplays between doping, solubility, segregation, and formation of secondary phases. Unlike previously held assumptions, we will demonstrate conclusively that the NASICON structure has in fact limited solubility for divalent dopants, which will in fact mostly dissolve into the secondary precipitation phases at grain boundaries, such as Na₃PO₄. We show that instead, divalent dopants modify the primary-secondary phase equilibria by modifying the Si/P ratio (and consequently, the Na concentration and space group) in the bulk and creating diffusion-assisting defects in the secondary phase. A maximum conductivity of 2.7 (±0.3) mS/cm was achieved with a Mg-doped NASICON with Si/P ratio of 2.2 which should be a viable candidate solid electrolyte for room-temperature rechargeable all-solid-state sodium-ion batteries. These insights pave the way for further composition tuning of earth-abundant NASICON compounds. Moreover, this study demonstrated the importance of simultaneous optimizing the primary (bulk) and secondary phases (plus the microstructure and interfaces) to achieve better overall performance, guided by the modeling of both phase formation and conductivity (vs. an overly-simplified assessment of the "doping" effect on conductivity via considering only the consequence of substituting cations in the primary bulk phase), which represents a strategy that should be generally adopted to improve other solid electrolytes.

2. Experimental methods

2.1. Synthesis

NASICON specimens with a nominal composition of Na_{3+2x}Zr₂₋

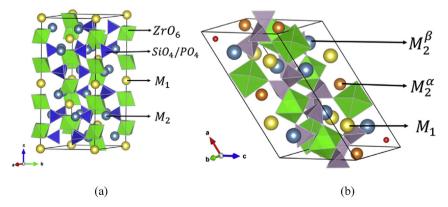


Fig. 1. Conventional unit cells of NASICON. (a) Rhombohedral structure (b) Monoclinic structure. The rhombohedral structure has two distinct Na⁺ sites: M₁ and M₂. The local Si/P environment and the monoclinic distortion splits the M₂ sites into two different sites: M_2^{α} and M_2^{β} labeled in the figure.

 $_{x}M_{x}Si_{2}PO_{12}$ ($M=Mg^{2+}$, Ni^{2+}) were prepared by a solid-state procedure using Na₂CO₃ (Fisher Scientific, 99.5%), ZrO₂ (Fisher Scientific, laboratory grade), SiO₂ (Alfa Aesar, 99.9%), NH₄H₂PO₄ (Sigma Aldrich, 99.99%), and MgO (Alfa Aesar, 99.95%) or NiO (Alfa Aesar, 99.998%) as precursors. The precursors were mixed using planetary ball mill in isopropanol for 24 h and then dried in an oven at 85 °C overnight. Calcination was performed at 1150 °C for 5 h with a heating rate of 5 °C/min in air. The calcined powders were manually ground using a pestle and mortar, followed by further grounding in a planetary ball mill in isopropanol for 48 h. The NASICON powders were then pressed using uniaxial pressing at about 2 metric tons (at a pressure of ~62 MPa) to form pellets of about 20 mm diameter and 3-4 mm thickness. Sintering was performed at 1230 °C and 1300 °C for 24 h with a heating rate of 5 °C/min for Na₃Zr₂Si₂PO₁₂ and Na_{3.2}Zr₂Si_{2.2}P_{0.8}O₁₂ series specimens, respectively. Extra powders of the same composition were placed both underneath and on the top of the pellets (so that the pellets were buried in the powders of identical composition) to (1) avoid the contamination from boat and (2) to reduce the evaporation. After sintering, both sides of pellets were polished to remove 0.5-1 mm material from top and bottom of each pellet to further ensure that the homogeneous parts of the pellets were used for conductivity measurements and other characterization. The relative densities of >90% were achieved for all sintered specimens with different compositions.

2.2. Characterization

X-ray diffraction (XRD) measurements of the specimens were performed using Cu K_{α} radiation to identify the crystalline phases. The microstructures of the cross sections of sintered pellets were observed using Scanning Electron Microscopy (SEM, FEI XL30) equipped with an energy-dispersive spectroscopy (EDS) analysis system (iXRF).

2.3. Conductivity measurement

Na-ion conductivity was measured with electrochemical impedance spectroscopy (EIS) using an impedance analyzer (Solartron 1255B) in the frequency range of 1 MHz to 1 Hz at 25, 0, -20, -40, -60 and -80 °C with Pt blocking electrodes sputtered on both sides of the pellets inside a temperature test chamber (LR Environmental Equipment Company) in dry air. Grain boundary, bulk and total conductivity were determined by fitting Nyquist plots (Figs. S1 and S2 in the Supplementary Information) using the Z-View software (Scribner, Inc.). Activation energies for specific grain boundaries, bulk and total conductivities were determined from fitting Arrhenius plots (Figs. S3 and S4 in the Supplementary Information).

3. Computational methods

3.1. Density functional theory calculations

All density functional theory (DFT) calculations were performed using Vienna Ab-initio Simulations Package (VASP) [23] within the Projector Augmented Wave (PAW) method. The Perdew-Burke-Ernzerhof (PBE) generalized gradient approximation was used to model the exchange-correlation functional. A plane-wave cut-off of 520 meV was applied with a k-point mesh $4\times4\times2$. An electronic energy tolerance of 5×10^{-5} eV/atom was used to relax the crystal structures. The Python Materials Genomics (pymatgen) [24] package was used for all input file generation and post-processing of results.

3.2. Diffusion energy barrier calculations for bulk undoped and doped NASICON

Vacancy diffusion barriers in a conventional NASICON cell were calculated using the climbing-image nudged elastic band (CI-NEB) method [25]. A Monkhorst-Pack k-point grid of $4 \times 4 \times 2$ was used. Atomic positions were relaxed until forces were smaller than 0.02 eV/Å. Charge neutrality, where necessary, was maintained via a compensating background charge.

3.3. Ab initio molecular dynamics (AIMD) simulations of Na₃PO₄

Due to the disorder in cubic Na_3PO_4 , the conductivity of Mg doped c- Na_3PO_4 was calculated using AIMD simulations. Non-spin-polarized AIMD simulations were conducted in the *NVT* ensemble at 800, 900, 1000, 1100, 1200 K. A plane-wave energy cutoff of 520 eV and Γ centered $1 \times 1 \times 1$ *k*-point mesh was adopted with 2 fs time steps. An in-house AIMD workflow software [26,27] was used to automate the calculations. The diffusivity (D) of Na^+ was calculated using the equation:

$$D = \frac{1}{2dt} \left\langle \left[\Delta \overrightarrow{r}(t) \right]^2 \right\rangle$$

where d is the dimensionality of diffusion; $[\Delta \vec{r}(t)]^2$ is the average mean square displacement (MSD) over a time duration t. The ionic conductivity, σ , is calculated using the Nernst-Einstein equation:

$$\sigma = \frac{\rho z^2 F^2}{RT} D_0 e^{-\Delta E_a/kT}$$

where ρ is the molar density of diffusing Na ions in the unit cell; z=1 is the charge of Na ions; F is the Faraday's constant; R is the gas constant and T is the temperature. D_o and ΔE_a are constants computed by fitting an Arrhenius relationship between diffusivities and temperatures. Room temperature diffusivity and conductivity were extrapolated from the computed quantities.

3.4. Dopant formation energy (E_f)

In order to determine which phase Mg segregates/dopes, we calculate the dopant formation energy, E_f , from first principles calculations. E_f is a measure of the thermodynamic energy cost function required to dope a host. It is defined as:

$$E_f = E_{doped} - E_{pristine} - \sum_{i=1}^{n} \mu_i N_i$$
 (1)

wherein, E_{doped} is the energy of the doped chemistry, $E_{pristine}$ is the energy of the undoped chemistry and μ_i is the chemical potential of the dopant. In the case of Mg doping of NASICON, we considered two possibilities:

$$Na_3Zr_2Si_2PO_{12} + 0.25 \text{ Mg} + 0.5 \text{ Na} \rightarrow Na_{3.5}Zr_{1.75}Mg_{0.25}Si_2PO_{12} + 0.25 \text{ Zr}$$
 (a)

$$Na_3PO_4 + 0.25 Mg \rightarrow Na_{2.5}Mg_{0.25}PO_{12} + 0.5 Na$$
 (b)

wherein, Equation (a) is the doping reaction expected when Mg substitutes Zr in NASICON while Equation (b) is the doping reaction when Mg substitutes Na in Na₃PO₄.

4 Results

4.1. Synthesis and phase identification

NASICON (Na $_3$ Zr $_2$ Si $_2$ PO $_{12}$) doped with different nominal atomic concentrations (0-0.9 at. %) of Mg were synthesized using solid-state methods (see Methods section for details). Henceforth, all Mg concentrations refer to at. % of Mg per formula unit of Na $_3$ Zr $_2$ Si $_2$ PO $_{12}$. It should be noted in this work, the term "doped" is used loosely to refer to NASICON synthesized with different overall atomic concentrations of Mg precursor added; as outlined in subsequent sections, both experimental and theoretical evidence demonstrate that the bulk NASICON crystal has limited solubility for Mg.

Fig. 2a shows the X-ray diffraction patterns of the undoped and Mg-doped NASICONs. In agreement with previous experimental reports, Na₃PO₄ and ZrO₂ phases are the main impurity phases, which were labeled by "•" and "*", respectively, in XRD patterns of undoped and Mg-doped NASICON specimens [4]. Slow-scan XRD experiments reveal that the peak correlated with monoclinic C2/cNASICON (at about 19°) is evolving even at low Mg dopant concentrations (Fig. 2b). The change in the shape of this peak has previously been used to study the phase transformation in NASI-CON from monoclinic (C2/c space group) to rhombohedral ($R\overline{3}c$ space group) at high temperatures. In addition, the intensity of the peak associated with cubic γ-Na₃PO₄ phase (at about 21°) increases with increasing nominal concentrations of Mg in the specimen (Fig. 2c). A phase profile fitting of the XRD pattern reveals the three main phases formed in the 0.128 at. % Mg-doped specimen to be C2/ c NASICON, ZrO₂ and Mg-doped γ-Na₃PO₄ (Fig. 2d). Further increase in Mg concentration leads to transformation of the NASICON from the monoclinic to rhombohedral phase, eventually resulting in decomposition to Na₄Zr₂(SiO₄)₃, NaMgPO₄ and ZrO₂ phases in specimen at 0.9 at. % of Mg. A very similar trend is also observed in XRD patterns of Ni-doped NASICON specimens (Fig. S5 in Supplementary Information).

4.2. Microstructure analysis

Fig. 3 shows an SEM image of the microstructure of 0.256 at. % Mg-doped NASICON. Three different phases with distinct contrasts are observed in the SEM images. The phase with a very bright contrast can be attributed to ZrO₂ phase. EDS analysis reveals that Mg is not uniformly distributed in these phases and is mostly segregated in a phase depleted of Si and enriched in Na. Due to the overlap of Zr L_{α} (2.04 KeV) and P K_{α} (2.02 KeV) lines, the EDS peaks for Zr and P overlap therefore one elemental map is shown for P/Zr elements in Fig. 3e. The non-uniform distribution of Mg is also observed in specimen with lower concentration of Mg (0.128 at. %), as shown in Fig. S6 in Supplementary Information. These observations suggest that Mg has a low solubility in the NASICON structure, and instead tends to dissolute more (preferentially "segregate") to the Si-poor secondary phase at grain boundaries. The non-uniform distribution of dopant is also observed in Nidoped NASICON specimens (Fig. S7 in Supplementary Information).

To confirm these observations, we calculated the dopant formation energies of Mg in both the bulk phase (Na₃Zr₂Si₂PO₁₂) and the precipitation phase at grain boundaries (γ-Na₃PO₄) using DFT calculations. In the bulk Na₃Zr₂Si₂PO₁₂ phase, the Mg dopant is found to prefer the Zr site with the creation of chargecompensating Na interstitials, with a dopant formation energy of 1.12 eV for a Mg:O ratio of 0.0208. In the secondary γ -Na₃PO₄ phase that forms at grain boundaries, Mg substitutes for Na with the creation of vacancies with a lower dopant formation energy of 0.85 eV at a much higher Mg:O ratio of 0.0625. These DFT results suggest that Mg doping should preferentially dissolute (segregate) into the secondary γ-Na₃PO₄ precipitation phase at grain boundaries than the bulk Na₃Zr₂Si₂PO₁₂ phase, especially if Na loss during high temperature synthesis reduces the Na chemical potential, which would promote the formation of Na vacancies over Na interstitials.

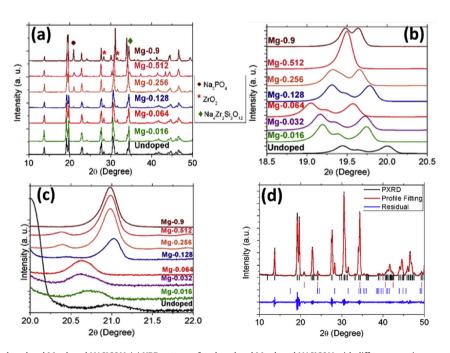


Fig. 2. Phase identification of undoped and Mg-doped NASICON. (a) XRD pattern of undoped and Mg-doped NASICON with different atomic percentages of Mg; (b) High-resolution XRD patterns showing the evolution of NASICON crystal structure from C^2/c (monoclinic) to R^3 c space group (rhombohedral) in Mg-doped NASICON specimens with different Mg concentration; (c) High-resolution XRD patterns showing the Na₃PO₄ phase peak in undoped and Mg-doped NASICON specimens with different Mg concentration; (d) Phase profile fitting of Mg-doped NASICON (Na_{3.256}Mg_{0.128}Zr_{1.872}Si₂PO₁₂) representing three main phases formed: C^2/c NASICON, ZrO₂ and Mg-doped γ -Na₃PO₄.

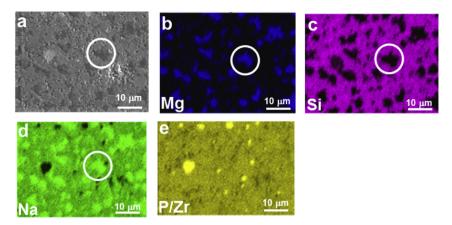


Fig. 3. (a) SEM image of Mg-doped NASICON (Na_{3.512}Mg_{0.256}Zr_{1.744}Si₂PO₁₂), along with individual EDS elemental maps of (b) Mg, (c) Si, (d) Na and (e) P/Zr. Due to the overlap of Zr L_{α} (2.04 KeV) and P K_{α} (2.02 KeV) lines, one EDS elemental map is used to represent the sum of the X-ray signals from both elements.

4.3. Ionic conductivity

Fig. 4a shows the total ionic conductivity of Mg-doped NASICON (0-0.9 at. %) at room temperature (25 °C). The total ionic conductivity increases slightly at low concentrations of Mg reaching a maximum ionic conductivity of 2.05 mS/cm at 0.128 at. % of Mg and decreases with a further increase in the Mg concentration. The bulk conductivity, apparent grain boundary conductivity, and specific grain boundary conductivity determined via Brick Layer Model (BLM) are also shown in Fig. 4a. The bulk conductivity increases sharply with the increasing overall Mg composition below 0.064 at. %. The conductivity only increases slightly from 0.064% to 0.128 at. % and then decreases with further increasing Mg doping; the decrease can be attributed to the phase transformation of NASICON crystal structure from C2/c (monoclinic) to $R\overline{3}$ c space group (rhombohedral) in Mg-doped NASICON specimens, which is discussed in more detail later. The grain boundary conductivity, on the other hand, peaks at 0.128 at. % Mg, and decreases with higher Mg concentrations. These trends are also reflected in the bulk, grain boundary and total activation barriers for Na conduction (Fig. 4b). The minimums in grain boundary and total activation barriers are observed at 0.128 at. % Mg, and increases with higher Mg concentrations. We should also note that although Mg (and Ni) doping reduced the detrimental effects of insulating grain boundaries/ secondary phases, the specific grain boundary conductivity (with the improvement due to doping) is still substantially lower than the bulk conductivity in the current case so that the total conductivity is lower than the bulk conductivity (Fig. 4a). Thus, a coarser microstructure should still be preferred for improving the total ionic conductivity in the current systems.

Here, we again emphasize that the so-called "grain boundary conductivity" measured by EIS in fact include contributions from grain boundaries, secondary phases, and other microstructural features, while we still call it "grain boundary" conductivity for simplicity, following the convention used in literature.

Conductivity measurements using non-blocking (Na metal) electrodes was performed on Mg-doped NASICON (Na_{3.256}Mg_{0.128}Zr_{1.872}Si₂PO₁₂) at 25 °C to verify the conductivity of Mg-doped NASICON is ionic (see Supplementary Fig. S13). A total conductivity of about 1.9 mS/cm was achieved, which is close to the values obtained by Pt blocking electrodes (2.07 mS/cm).

4.4. Role of Mg doping on bulk and secondary phase (grain boundary) conductivity: hypotheses supported by AIMD modeling

From the results in the preceding sections, we may surmise that although Mg does not have significant solubility in the bulk $Na_3Zr_2Si_2PO_{12}$ phase, it nevertheless has a significant impact on both the bulk and "grain boundary" conductivities and activation energies. These seemingly contradictory observations can be reconciled by considering the effect of Mg on the synthesized primary (bulk) and secondary phase equilibria. It is well-known that the NASICON structure exists in a range of compositions with formula $Na_{1+x}Zr_2Si_xP_{3-x}O_{12}$ with different Si/P ratios and correspondingly different Na concentrations. We therefore propose that the addition of the MgO precursor results in the formation of a bulk

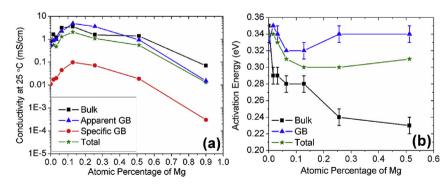


Fig. 4. (a) Bulk, apparent GB conductivity, specific GB conductivity and total ionic conductivity at room temperature (25 $^{\circ}$ C) for undoped and Mg-doped NASICON (Na₃Zr₂Si₂PO₁₂ based series). The estimated errors of conductivities are $\pm 10\%$. (b) Activation energies of grain boundary, bulk and total conductivities for undoped and Mg-doped NASICON (Na₃Zr₂Si₂PO₁₂ based series). Error bars are standard errors based on 95% confidence level.

phase with a higher Si/P ratio (and higher Na concentration) and a Mg-doped Na₃PO₄ secondary phase.

To understand the role of Si/P ratio on the activation energy, we performed climbing image-nudged elastic band calculations (CI-NEB) to determine the alkali vacancy diffusion energy barriers for monoclinic NASICON Na_{1+x}Zr₂Si_xP_{3-x}O₁₂ for 1.75 $\leq x \leq$ 2.25. It has been well established that outside this range of Si concentration. NASICON chemistries have much lower ionic conductivities [1,28,29]. Table 1 tabulates the vacancy diffusion energy barriers for NASICON chemistries with x = 1.75, 2.0 and 2.25. At x = 2, the maximum barrier along the percolating path (Fig. S8 in the Supplementary Information) was found to be 183 meV. When P content is increased to 1.25 (x = 1.75), the energy barrier in the local environment increases significantly to 385 meV. Conversely, when the Si content is increased to x = 2.25, the barrier decreases slightly to 180 meV. The CI-NEB barrier plots can be found in Fig. S9 and Fig. S10 in Supplementary Information. Thus, within the monoclinic range of Si concentration, it is important that molar concentration of Si must be higher than 2.0 to achieve maximum bulk conductivity

To investigate the effect of Mg doping on the conductivity of the secondary γ -Na₃PO₄ phase (that precipitates at grain boundaries and contributes to the "grain boundary conductivity" measured by EIS), ab initio molecular dynamics (AIMD) calculations were carried out on Mg-doped γ -Na₃PO₄ (Na_{2.5}Mg_{0.25}PO₄) as well as t-Na₃PO₄. Fig. 5 shows the Arrhenius relationship of diffusivity with temperature for γ-Na_{2.5}Mg_{0.25}PO₄. The extrapolated bulk conductivity of Na_{2.5}Mg_{0.25}PO₄ at room temperature (300 K) is 0.047 mS/cm, and the predicted activation energy is 376 meV. In contrast, t-Na₃PO₄ exhibits negligible diffusivity even at 800-1200K in the AIMD simulations (Fig. S11 in the Supplementary Information), and its activation energy has previously been reported to be ~760 meV [30]. The modest ionic conductivity of Mg-doped γ -Na₃PO₄ helps in decreasing the effective grain boundary resistance of Na diffusion in the GB as compared to the (insulating) secondary ZrO₂ and t-Na₃PO₄ phases in undoped NASICON GBs.

4.5. Experimental validation of hypotheses and synthesis of high-conductivity NASICON

To further confirm the above hypotheses experimentally, monoclinic NASICON specimens with a higher nominal Si/P ratio of 2.2/0.8 were synthesized with and without Mg doping. The undoped NASICON, with a nominal formula of Na_{3.2}Zr₂Si_{2.2}P_{0.8}O₁₂, was found to have a bulk ionic conductivity of 5.66 mS/cm, slightly higher than that of undoped Na₃Zr₂Si₂PO₁₂ with Si:P ratio of 2 (5.06 mS/cm). Further, the maximum total ionic conductivity achieved in Mg-doped NASICON (Si-2.2 version: 2.7 mS/cm at 0.0625 at. % Mg) is about 30% higher than the one achieved in Mg-doped NASICON (Si-2.0 version: 2.05 mS/cm at 0.125 at. % Mg). Note that the maximum total ionic conductivity in the Si-2.2 version is obtained at much lower concentration of Mg compared to the Si-2.0 version given that even a small depletion of P from the bulk into the

Table 1 Climbing Image Nudged Elastic Band (CI-NEB) calculation of vacancy diffusion barriers in NAICON chemistries. Si/P compositions of 1.75/1.25 and 2.25/0.75 were constructed from the structure of Si/P: 2.0/1.0 by substituting one Si/P in Na $_{12}$ Zr $_{8}$. Si $_{8}$ (PO $_{12}$) $_{4}$ accompanied by the addition of vacancy/Na $^{+}$ appropriately. In the case of Si/P: 2.25/0.75 and Si/P:1.75/1.25, the barriers were computed in the vicinity of the substituted Si/P as compared to the nominal composition of Si/P:2.0/1.0. It is assumed that the other paths in the framework are not affected by the introduction of Si/P and the accompanying Na $_{+}$ /vacancy respectively.

Si/P Composition	Si/P: 1.75/1.25	Si/P: 2.0/1.0	Si/P: 2.25/0.75
CI-NEB Barrier (meV)	385	183	180

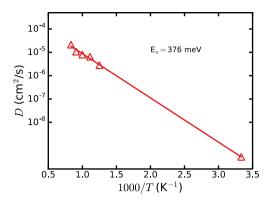


Fig. 5. Arrhenius plot of diffusivity in $Na_{10}MgP_4O_{12}$ computed from *ab initio* molecular dynamics. Simulations were performed at 800, 900, 1000, 1100 and 1200 K with room temperature diffusivity being calculated via extrapolation.

secondary Na₃PO₄ phase at grain boundaries is likely to result in a change from the monoclinic structure to the lower-conductivity rhombohedral structure [1]. Similar synthesis of Ni doped NASI-CON with Si:P ratio of 2.2/0.8 was found to achieve a maximum ionic conductivity of 2.3 mS/cm, as shown in Fig. 6.

5. Discussion

In this work, we demonstrated the synthesis of a highconductivity monoclinic C2/c NASICON via the introduction of aliovalent dopants such as Mg²⁺ and Ni²⁺. We present clear experimental and computational evidence that the effect of aliovalent dopants are more complex than that has been previously assumed. The commonly held assumption in previous works is that any dopants introduced would sit in either the Zr⁴⁺ or Na⁺ sites, resulting in a modification of the bulk activation barriers and/or Na⁺ concentration. Our EDS results and calculated dopant formation energies suggest that dopants are more likely to incorporate into a secondary phase precipitated at grain boundaries, such as Na₃PO₄, and any effect on the bulk activation barriers result from changes in the Si:P ratio within the bulk. Indeed, CI-NEB calculations confirm the lowering of the bulk activation barriers with increase in Si/P ratio, subject to the restriction that Si/P must be less than 2.2 to prevent transformation to the lower-conducting rhombohedral phase. This is consistent with previous experimental results by Ahmad et al. reporting maximum room temperature bulk ionic conductivity for the NASICON for a Si/P ratio of 2.2/0.8 [28]. On the other hand, CI-NEB calculations performed on

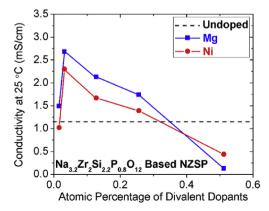


Fig. 6. Total ionic conductivity at room temperature (25 °C) of undoped and doped (Mg/Ni) NASICON (Na_{3.2}Zr₂Si_{2.2}P_{0.8}O₁₂) with different atomic percentages of Mg/Ni.

Mg-doped NASICON (where Mg is assumed to sit in the Zr site) find that bulk activation barriers in the vicinity of the dopant increases significantly from 183 meV to 407 meV (see Fig. S12 (a) in Supplementary Information), directly contradicting previously held assumptions that aliovalent dopants decrease the bulk activation energies. Similarly, CI-NEB calculations performed on Ni-doped NASICON also shows that the activation energy increases to 458 meV in the vicinity of the dopant (See Fig. S12 (b) in Supplementary Information).

Though the introduction of aliovalent dopants does have an indirect effect on the bulk conductivity by modifying the Si/P ratio, it has a far more important effect on the effective grain boundary conductivity. Like many oxide superionic conductors, the bulk conductivity is not the limiting bottleneck in the NASICON phases, and bulk conductivities in excess of 1 mS/cm have been reported by Ahmad et al. since 1987 [28]. The EIS results in this work (Fig. 4) clearly show a substantial improvement in the effective grain boundary conductivity upon doping, which is validated by AIMD simulations showing significant improvement in the conductivity of the secondary phase at grain boundaries. Indeed, it is our belief that similar effects are present in previous reports of enhanced total conductivity in NASICON with other dopants such as Sc³⁺ and Y³⁺ [4,22,31]. Table S1 in Supplementary Information shows the dopant formation energies in the bulk NASICON and the predicted secondary phase (that presumably precipitates at grain boundaries) for these dopants; similarly, a higher dopant solubility is predicted for the secondary phase compared to the primary bulk phases.

It should be noted that during the course of this manuscript preparation, a very recent report of Mg-doped NASICON published. claiming a conductivity of 3.5 mS/cm at room temperature for a low doping level of 0.05 at. % Mg [32]; however, our measurements showed that specimens with a similar composition (0.064 at. % Mg) only have conductivity of ~1.3 mS/cm, which we believe to be a more reasonable value since at these low doping concentrations, the nominal concentration of Na is lower than undoped NASICON (Si-2.2 version). In addition, the conductivity of undoped NASICON is not reported in that study, making it difficult to assess the actual improvement upon doping and effects of other factors. We also notice an unusual high contact resistance (120 Ω) in the Nyquist plot in that report [32], which should have been deducted from total resistivity to calculate the conductivity of Mg-doped NASICON, but may cause some measurement errors. Moreover, authors attributed the improvement in conductivity to the increased bottleneck size (being related to a pseudo-hexagonal ring consisting of alternating three ZrO₆ octahedra and three SiO₄/PO₄ tetrahedra) for ion conduction, which is likely an overly-simplified explanation. While isovalent doping can be purely attributed to structural changes [33], it is generally believed that the effects of aliovalent doping on conductivity involves complex interactions of an increased concentration of mobile species, as well as modified electronic density and framework structure, albeit the additional (yet important) effects on solubility, phase transformation, and secondary phase discovered in this study. For example, a recent study of Al-doped LiTi₂(PO₄)₃ [34] has shown that the activation energy along the diffusion pathway actually increases in the vicinity of the dopant. Our CI-NEB calculations performed on Mg/Nidoped NASICON (where Mg/Ni is assumed to sit in the Zr site) also finds that bulk activation barriers in the vicinity of the dopant increases significantly as discussed above. Similar to previous reports [5], a high GB conductivity was also reported, for which the authors did not provide any explanation [32].

Separating the bulk and GB conductivities, we have shown that the effective GB conductivity of Mg-doped NASICON is also improved in comparison with undoped NASICON. Such improvements in the GB conductivity of aliovalent-doped NASICON has

been observed previously (in the normalized Nyquist plots in Fig. 1a and b in reference [4] and table 2 in reference [5]); but, unfortunately, these observations have not been fully recognized and elaborated in previous studies [4,5]. Moreover, adding ZnO as a sintering aid to NaZr₂(PO₄)₃ was proposed to improve the density of ceramic by creating positively charged oxygen vacancies to maintain charge neutrality with negatively charged zinc substituted on Zr sites [35]. Here, it was suggested that oxygen vacancies may reduce the structural perfection of sodium zirconium phosphate to improve the sintering behavior in presence of zinc oxide [35]. However, in our cases, the densities of sintered specimens with different atomic concentrations of divalent dopants were all about 90% of theoretical density; thus, the improvements in grain boundary conductivity cannot be simply attributed to improved densities. In addition, our EDS results and calculated dopant formation energies suggest that dopants are more likely to be incorporated in a secondary phase at grain boundaries, such as Na₃PO₄. The high GB resistivity of NASICON is mostly attributed to the secondary ZrO₂ phase precipitated at GBs due to evaporation of Na and P during high temperature synthesis and sintering of NASICON [18–20]. However, the ZrO₂ phase is also reported to form in NASICON sintered by field assisted sintering technique (FAST) with very short exposure to high temperatures [36]. It is difficult to separate out the grain boundary and bulk conductivity at high temperatures for superionic conductors due to electrode effects and inductions from connections and measurement cell [37]. A similar behavior, i.e., a very low resistivity of grain boundaries at high temperatures and high resistivity at intermediate and low temperatures, was reported for NASICON [18,29]. Na₃PO₄ is another phase that often precipitate at grain boundaries of NASICON. Its cubic phase (y phase) stabilized at high temperatures is considered as solid electrolyte for high temperature applications (Na-S batteries) [30,38-40], while its low-temperature phase (tetragonal Na₃PO₄) has an extremely low ionic conductivity at intermediate and low temperatures. The low conductivity is attributed to the compact crystal structure of Na₃PO₄ and low concentrations of Na vacancies. As shown in this work, aliovalent dopants such as Mg²⁺ tend to displace Na in the secondary Na₃PO₄ phase at grain boundaries, creating Na vacancies. We further speculate that this Na displacement from the GB phase results in the injection of Na into the vacant sites in the NASICON crystal structure. This is somewhat analogous to previously investigated mixed-phase ionic conductors show a higher ionic conductivity than those of the parent phases in Ag⁺ ionic conductors [41,42] and in F⁻ ion conductors [43-45]. It is possible that a unilateral distribution of charge carrier (Na⁺) from Mg-doped Na₃PO₄ phase into vacant sites in NASICON structure that improves the ionic conductivity of NASICON. Comparing normalized Nyquist plots at 25 °C for Mg 0.128 at. % and Mg 0.256 at. % specimens (Fig. S1 in Supplementary Information), it is obvious that both bulk and grain boundary conductivity decreases at higher concentrations due to coarsening of Mg-doped Na₃PO₄ phase. This is presumably due to 1) a depletion of P in the primary NASICON bulk phase and formation of $R\overline{3}$ c NASICON that decreases the bulk conductivity and 2) a decrease in volume fraction of NASICON/Mg-doped Na₃PO₄ interface. The conductivity drop at high concentrations of aliovalent-doped NASICON (Sc3+-doped NASICON) [5] was previously attributed to decrease in Na vacant sites in NASICON structure; we speculate that the maximum conductivity achieved in Mg-doped NASICON is limited by size and distribution of secondary Mg-doped Na₃PO₄ phase at grain boundaries in NASICON, following to a percolation theory for composite ionic conductors.

It is also possible that a Na₃PO₄-based, nanoscale, interfacial phase formed in doped NASICON materials, serving as an additional reason for improved effective grain boundary conductivity. A

similar case has been reported previously, where the formation of 1–4 nm-thick, LaP₃O₉-based, interfacial phases at grain boundaries in LaPO₄ increased the proton conductivity by more than 10 times [46]. Moreover, the formation of Li₄P₂O₇- or Li₃PO₄-based nanoscale surface phases have been shown to improve the rate capabilities of Li-ion batteries [47,48], pseudocapacitors [49] and a similar surface phase was recently found to improve the oxygen ionic conductivity of nanofibers by more than 1000 times [50], see a recent review for relevant discussion [51]. Unfortunately, these NASICON materials are extremely sensitive to electron and ion beams, preventing us from conducting direct atomic-resolution characterization of grain boundaries (as the NASICON specimens, particularly their grain boundaries, can be damaged by the highenergy electron beam in TEM or even in high-magnification SEM). Thus, it is extremely challenging, if not infeasible, to confirm whether a similar Na₃PO₄-based, nanoscale interfacial phase formed and played a role in improving the grain boundary ionic conductivity directly through HRTEM in the current case and further discussion is thus unwarranted at this time.

Finally, this work suggested that there are significant opportunities to improve both bulk and grain boundary conductivity of solid electrolytes via controlling the microstructure (e.g., the size and distribution of the secondary phase(s) precipitated at grain boundaries) as well as interfacial engineering. Moreover, prior studies have been successfully taken advantages of twodimensional heterostructures (that is beneficial if and only if the interfacial ionic conductivity is higher the bulk conductivity) [52] or textured columnar grains (that may minimize the detrimental grain boundary blocking effects if the grain boundary conductivity is significantly lower than the bulk conductivity) [53] to achieve much improved conductivities along one direction. Specific for this case, we expect that well-controlled microstructures and further interfacial engineering, e.g., via forming conductive nanoscale (thermodynamically 2-D) interfacial phase (complexion) [51], may help to achieve even higher Na ionic conductivity for doped NASICON. The assembly of this and early studies collectively suggest the important opportunities to achieve superior ionic conductivities via controlling and tailoring microstructure and interfaces, in addition to the phase and doping of the primary bulk phases.

6. Conclusion

To summarize, we have studied the effects of aliovalent doping on both bulk and GB conductivity of NASICON using both experimental and computational techniques. Based on these studies, Mg and Ni doped NASICONs with the optimized total ionic conductivities of 2.7 mS/cm and 2.1 mS/cm, respectively, were synthesized. Our results show that higher concentrations of the Mg or Ni dopant promote the formation of a Na₃PO₄-based secondary phase. This simultaneously leads to a change in the Si/P composition in the bulk phase, which increases the bulk ionic conductivity initially (but eventually ending up with lower conducting R3c phase NASICON with high doping level). More importantly, the dopant containing Na₃PO₄-based secondary phase formed at grain boundaries reduces the effective grain boundary resistance, thereby increasing the total ionic conductivity. This study suggests significant opportunities to improve the total conductivity via controlling the phase and chemistry of both the primary and secondary phases via doping, as well as tailoring the interfaces and microstructure.

Acknowledgement

We gratefully acknowledge the financial support from the National Science Foundation under a DMREF grant no. CMMI-

1436976.

M.S. and B.R. contributed equally to this work. Correspondence should be addressed to: J.L. (jluo@alum.mit.edu) and S.P.O. (ongsp@eng.ucsd.edu).

Appendix A. Supplementary data

Supplementary data related to this article can be found at http://dx.doi.org/10.1016/j.jpowsour.2017.02.042.

References

- [1] J.B. Goodenough, H.Y.P. Hong, J.A. Kafalas, Fast Na+-Ion transport in skeleton structures, Mater. Res. Bull. 11 (1976) 203—220, http://dx.doi.org/10.1016/ 0025-5408(76)90077-5.
- [2] H.Y.P. Hong, Crystal-structures and crystal-chemistry in system Na1+Xzr2-sixp3-Xo12, Mater. Res. Bull. 11 (1976) 173-182, http://dx.doi.org/10.1016/0025-5408(76)90073-8.
- [3] L. Vijayan, G. Govindaraj, Structural and electrical properties of high-energy ball-milled NASICON type Li1.3Ti1.7Al0.3(PO4) 2.9(VO4)0.1 ceramics, J. Phys. Chem. Solids 72 (2011) 613-619, http://dx.doi.org/10.1016/ j.jpcs.2011.02.001.
- [4] A.G. Jolley, G. Cohn, G.T. Hitz, E.D. Wachsman, Improving the ionic conductivity of NASICON through aliovalent cation substitution of Na3Zr2Si2PO12, Ionics (Kiel) 21 (2015) 3031–3038, http://dx.doi.org/10.1007/s11581-015-1498-8.
- [5] Q. Ma, M. Guin, S. Naqash, C.-L. Tsai, F. Tietz, O. Guillon, Scandium-substituted Na3Zr2(SiO4)2(PO4) prepared by a solution-assisted solid-state reaction method as sodium-ion conductors, Chem. Mater. 0 (n.d.) null. http://dx.doi. org/10.1021/acs.chemmater.6b02059.
- [6] T. Salkus, A. Dindune, Z. Kanepe, J. Ronis, A. Urcinskas, A. Kezionis, A.F. Orliukas, Lithium ion conductors in the system Li(1+y)Ge(2-x-y)Ti(x) Aly(PO4)(3) (x=0.1 divided by 0.3, y=0.07 divided by 0.21), Solid State Ionics 178 (2007) 1282–1287.
- [7] M. Jansen, U. Henseler, Synthesis, structure determination, and ionic-conductivity of sodium tetrathiophosphate, J. Solid State Chem. 99 (1992) 110–119, http://dx.doi.org/10.1016/0022-4596(92)90295-7.
- [8] A. Hayashi, K. Noi, N. Tanibata, M. Nagao, M. Tatsumisago, High sodium ion conductivity of glass ceramic electrolytes with cubic Na3PS4, J. Power Sources 258 (2014) 420–423, http://dx.doi.org/10.1016/j.jpowsour.2014.02.054.
- [9] A. Hayashi, K. Noi, A. Sakuda, M. Tatsumisago, Superionic glass-ceramic electrolytes for room-temperature rechargeable sodium batteries, Nat. Commun. 3 (2012) doi:Artn 85610.1038/Ncomms1843.
- [10] W.D. Richards, T. Tsujimura, L.J. Miara, Y. Wang, J.C. Kim, S.P. Ong, I. Uechi, N. Suzuki, G. Ceder, Design and Synthesis of the Superionic Conductor Na10SnP2S12, 2016, p. 7.
- [11] W.D. Richards, T. Tsujimura, L. Miara, Y. Wang, J.C. Kim, S.P. Ong, I. Uechi, N. Suzuki, G. Ceder, Design and synthesis of the superionic conductor Na10SnP2S12, Nat. Commun. 7 (2016) 1–8, http://dx.doi.org/10.1038/ ncomms11009.
- [12] G. Sahu, C. Liang, Crystalline sulfide electrolytes for Li-S batteries, in: Handb. Solid State Batter, n.d.: pp. 365–389. http://dx.doi.org/10.1142/ 9789814651905_0011.
- [13] F. Mauvy, E. Siebert, P. Fabry, Reactivity of {NASICON} with water and interpretation of the detection limit of a {NASICON} based Na+ ion selective electrode, Talanta 48 (1999) 293–303, http://dx.doi.org/10.1016/S0039-9140/98100234-3.
- [14] R.O. Fuentes, F. Figueiredo, F.M.B. Marques, J.I. Franco, Reaction of NASICON with water, Solid State Ionics 139 (2001) 309—314, http://dx.doi.org/10.1016/ S0167-2738(01)00683-X.
- [15] B. Radhakrishnan, S.P. Ong, Aqueous stability of alkali superionic conductors from first principles calculations, Front. Energy Res. 4 (2016) 1–12, http:// dx.doi.org/10.3389/fenrg.2016.00016.
- [16] W. Bogusz, F. Krok, W. Jakubowski, Bulk and grain boundary electrical conductivities of NASICON, Solid State Ionics 2 (1981) 171–174, http://dx.doi.org/10.1016/0167-2738(81)90175-2.
- [17] O. Bohnke, S. Ronchetti, D. Mazza, Conductivity measurements on nasicon and nasicon-modified materials, Solid State Ionics 122 (1999) 127–136, http:// dx.doi.org/10.1016/S0167-2738(99)00062-4.
- [18] W. Bogusz, F. Krok, W. Jakubowski, Bulk and grain boundary electrical conductivities of NASICON, Solid State Ionics 2 (1981) 171–174, http://dx.doi.org/10.1016/0167-2738(81)90175-2.
- [19] R. Fuentes, F.M. Figueiredo, F.M.B. Marques, J.I. Franco, Influence of microstructure on the electrical properties of NASICON materials, Solid State Ionics 140 (2001) 173–179, http://dx.doi.org/10.1016/S0167-2738(01)00701-9.
- [20] Z.-Z. Zhang, S.-Q. Shi, Y.-S. Hu, L.-Q. Chen, Sol-gel synthesis and conductivity properties of sodium ion solid state electrolytes Na3Zr2Si2PO12, J. Inorg. Mater 28 (2013) 1255–1260, http://dx.doi.org/10.3724/SP.J.1077.2013.13120.
- [21] A.G. Jolley, D.D. Taylor, N.J. Schreiber, E.D. Wachsman, Structural investigation of monoclinic-rhombohedral phase transition in Na3Zr2Si2PO12 and doped NASICON, J. Am. Ceram. Soc. 98 (2015) 2902–2907, http://dx.doi.org/10.1111/

iace.13692.

- [22] W.G. Coors, J.H. Gordon, S.G. Menzer, Electrochemical Cell Comprising Ionically Conductive Membrane and Porous Multiphase Electrode, 2012. http://www.google.com/patents/US8338038.
- [23] G. Kresse, J. Furthmüller, Efficient iterative schemes for ab initio total-energy calculations using a plane-wave basis set, Phys. Rev. B. Condens. Matter 54 (1996) 11169–11186, http://dx.doi.org/10.1103/PhysRevB.54.11169.
- [24] S.P. Ong, W.D. Richards, A. Jain, G. Hautier, M. Kocher, S. Cholia, D. Gunter, V.L. Chevrier, K.A. Persson, G. Ceder, Python Materials Genomics (pymatgen): a robust, open-source python library for materials analysis, Comput. Mater. Sci. 68 (2013) 314–319, http://dx.doi.org/10.1016/j.commatsci.2012.10.028.
- [25] G. Henkelman, B.P. Uberuaga, H. Jónsson, A climbing image nudged elastic band method for finding saddle points and minimum energy paths, J. Chem. Phys. 113 (2000) 9901, http://dx.doi.org/10.1063/1.1329672.
- [26] A. Jain, S.P. Ong, W. Chen, B. Medasani, X. Qu, M. Kocher, M. Brafman, G. Petretto, G.-M. Rignanese, G. Hautier, D. Gunter, K.A. Persson, FireWorks: a dynamic workflow system designed for highthroughput applications, Concurr. Comput. Pract. Exp. 27 (2015) 5037–5059, http://dx.doi.org/10.1002/cpe.3505.
- [27] Z. Deng, B. Radhakrishnan, S.P. Ong, Rational composition optimization of the lithium-rich Li 3 OCl 1- x Br x anti-perovskite superionic conductors, Chem. Mater 27 (2015) 3749–3755, http://dx.doi.org/10.1021/acs.chemmater.5b00988.
- [28] A. Ahmad, T.A. Wheat, A.K. Kuriakose, J.D. Canaday, A.G. McDonald, Dependence of the properties of NASICONs on their composition and processing, Solid State Ionics 24 (1987) 89–97, http://dx.doi.org/10.1016/0167-2738(87) 90070-1.
- [29] O. Bohnke, S. Ronchetti, D. Mazza, Conductivity measurements on nasicon and nasicon-modified materials, Solid State Ionics 122 (1999) 127–136, http:// dx.doi.org/10.1016/S0167-2738(99)00062-4.
- [30] J.T.S. Irvine, A.R. West, Solid electrolytes based on Na3PO4:M2+ (M=Mg, Zn, Ca, Sr), Solid State Ionics 37 (1989) 73–78, http://dx.doi.org/10.1016/0167-2738/89)90290-7
- [31] R.E. Clausing, F. Waelbroeck, J. Winter, P. Wienhold, L. Kiinen, N. Noda, Surface structure determination by x-ray diffraction R. Feidenhans, L 0167-5729/89/ {\$} 29. 40 {@} Elsevier Science Publishers B. V. (North-Holland Physics Publishing Division), Surf. Sci. Rep. 10 (1989) 105–188.
- [32] S. Song, H.M. Duong, A.M. Korsunsky, N. Hu, L. Lu, A Na+ superionic conductor for room-temperature sodium batteries, Sci. Rep. 6 (2016) 32330, http:// dx.doi.org/10.1038/srep32330.
- [33] E.R. Losilla, M.A.G. Aranda, S. Bruque, M.A. París, J. Sanz, A.R. West, Under-standing Na mobility in NASICON materials: a rietveld, 23 Na and 31 P MAS NMR, and impedance study, Chem. Mater 10 (1998) 665–673, http://dx.doi.org/10.1021/cm970648j.
- [34] B. Lang, B. Ziebarth, C. Elsässer, Lithium ion conduction in LiTi 2 (PO 4) 3 and related compounds based on the NASICON structure: a first-principles study, Chem. Mater 27 (2015) 5040–5048, http://dx.doi.org/10.1021/acs.chemmater.5b01582.
- [35] M.V. Sukhanov, V.I. Pet'kov, D.V. Firsov, Sintering mechanism for high-density NZP ceramics, Inorg. Mater 47 (2011) 674–678, http://dx.doi.org/10.1134/ S0020168511060197.
- [36] J.-S. Lee, C.-M. Chang, Y.I.L. Lee, J.-H. Lee, S.-H. Hong, Spark plasma sintering (SPS) of NASICON ceramics, J. Am. Ceram. Soc. 87 (2004) 305–307, http://

- dx.doi.org/10.1111/j.1551-2916.2004.00305.x.
- [37] L. Zhang, F. Liu, K. Brinkman, K.L. Reifsnider, A.V. Virkar, A study of gadolinia-doped ceria electrolyte by electrochemical impedance spectroscopy, J. Power Sources 247 (2014) 947–960, http://dx.doi.org/10.1016/j.jpowsour.2013.09.036.
- [38] J.T.S. Irvine, A.R. West, Solid electrolytes based on Na3PO4 doped with S, Se, Mo, W, Mater. Res. Bull. 22 (1987) 1047–1054, http://dx.doi.org/10.1016/ 0025-5408(87)90233-9.
- [39] W.-G. Yin, J. Liu, C.-G. Duan, W.N. Mei, R.W. Smith, J.R. Hardy, Superionicity in \$\mathrm{Na}_{3}{\mathrm{PO}}_{4}\$: a molecular dynamics simulation, Phys. Rev. B 70 (2004) 64302. http://dx.doi.org/10.1103/PhysRevB.70.064302.
- [40] A. Hooper, P. McGeehin, K.T. Harrison, B.C. Tofield, Ionic conductivity of pure and doped Na3PO4, J. Solid State Chem. 24 (1978) 265–275, http://dx.doi.org/ 10.1016/0022-4596(78)90018-X.
- [41] K. Shahi, J.B. Wagner, Anomalous ionic conduction in AgBrAgI mixed crystals and multiphase systems, J. Phys. Chem. Solids 43 (1982) 713–722, http:// dx.doi.org/10.1016/0022-3697(82)90236-0.
- [42] K. Shahi, J.B. Wagner, Fast ion transport in silver halide solid solutions and multiphase systems, Appl. Phys. Lett. 37 (1980).
- [43] N. Sata, N.Y. Jin-Phillipp, K. Eberl, J. Maier, Enhanced ionic conductivity and mesoscopic size effects in heterostructures of BaF2 and CaF2, Solid State ionics. 154–155 (2002) 497–502, http://dx.doi.org/10.1016/S0167-2738(02) 00488-5.
- [44] N. Sata, K. Eberman, K. Eberl, J. Maier, Mesoscopic fast ion conduction in nanometre-scale planar heterostructures, Nature 408 (2000) 946–949, http:// dx.doi.org/10.1038/35050047
- [45] N.I. Sorokin, I.I. Buchinskaya, P.P. Fedorov, B.P. Sobolev, Electrical conductivity of a CaF2-BaF2 nanocomposite, Inorg. Mater 44 (2008) 189–192, http:// dx.doi.org/10.1134/S0020168508020192.
- [46] G. Harley, R. Yu, L.C. De Jonghe, Proton transport paths in lanthanum phosphate electrolytes, Solid State Ionics 178 (2007) 769–773, http://dx.doi.org/ 10.1016/j.ssi.2007.03.011.
- [47] B. Kang, G. Ceder, Battery materials for ultrafast charging and discharging, Nature 458 (2009) 190–193, http://dx.doi.org/10.1038/nature07853.
- [48] J. Huang, J. Luo, A facile and generic method to improve cathode materials for lithium-ion batteries via utilizing nanoscale surface amorphous films of selfregulating thickness, Phys. Chem. Chem. Phys. 16 (2014) 7786–7798, http:// dx.doi.org/10.1039/C4CP00869C.
- [49] M. Samiee, J. Luo, Pseudocapacitive properties of two-dimensional surface vanadia phases formed spontaneously on titania, ACS Appl. Mater. Interfaces 8 (2016) 12871–12880, http://dx.doi.org/10.1021/acsami.6b03569.
- [50] W. Liu, W. Pan, J. Luo, A. Godfrey, G. Ou, H. Wu, W. Zhang, Suppressed phase transition and giant ionic conductivity in La2Mo2O9 nanowires, Nat. Commun. 6 (2015) 8354, http://dx.doi.org/10.1038/ncomms9354.
- [51] J. Luo, Interfacial engineering of solid electrolytes, J. Mater 1 (2015) 22–32, http://dx.doi.org/10.1016/j.jmat.2015.03.002.
- [52] J. Maier, Nanoionics: ion transport and electrochemical storage in confined systems, Nat. Mater 4 (2005) 805–815, http://dx.doi.org/10.1038/nmat1513.
- [53] D. Pergolesi, E. Fabbri, A. D'Epifanio, E. Di Bartolomeo, A. Tebano, S. Sanna, S. Licoccia, G. Balestrino, E. Traversa, High proton conduction in grain-boundary-free yttrium-doped barium zirconate films grown by pulsed laser deposition, Nat. Mater 9 (2010) 846–852, http://dx.doi.org/10.1038/nmat2837.